









	<h2 style="color: red;">RFD14N05</h2>
 <p>Image may be representation. See specs for product details.</p>	Hersteller-Teilenummer: RFD14N05
	Hersteller / Marke: AMI Semiconductor / ON Semiconductor
	Teil der Beschreibung: MOSFET N-CH 50V 14A I-PAK
	Datenblätter:  RFD14N05.pdf
	RoHs Status: Bleifrei / RoHS-konform
	Lagerzustand: New original, 33665 pcs Stock Available.
	Liefern von: Hong Kong
Versandweg: DHL/Fedex/TNT/UPS/EMS	

Spezifikationen

Teilenummer	RFD14N05
Hersteller	AMI Semiconductor / ON Semiconductor
Beschreibung	MOSFET N-CH 50V 14A I-PAK
Kategorie	Diskrete Halbleiterprodukte > Transistoren-FETs ,
Teilstatus	33665 pcs Stock
detaillierte Beschreibung	N-Channel 50V 14A (Tc) 48W (Tc) Through Hole TO-
Serie	-
Technologie	MOSFET (Metal Oxide)
Betriebstemperatur	-55°C ~ 175°C (TJ)
Befestigungsart	Through Hole
Verpackung / Gehäuse	TO-251-3 Short Leads, IPak, TO-251AA
Supplier Device-Gehäuse	TO-251AA
Verlustleistung (max)	48W (Tc)
Typ FET	N-Channel
FET-Merkmal	-
Drain-Source-Spannung (Vdss)	50V
Strom - Ununterbrochener Abfluss (Id) bei 25 ° C	14A (Tc)
Rds On (Max) @ Id, Vgs	100 mOhm @ 14A, 10V
VGS (th) (Max) @ Id	4V @ 250µA
Gate Charge (Qg) (Max) @ Vgs	40nC @ 20V
Eingabekapazität (Ciss) (Max) @ Vds	570pF @ 25V
Antriebsspannung (Max Rds On, Min Rds On)	10V
Vgs (Max)	±20V
Verpackung	Tube
Bleifreier Status / RoHS-Status	Lead free / RoHS Compliant
Feuchtigkeitsempfindlichkeitsniveau (MSL)	1 (Unlimited)



















































RFD14N05 ist neu im Original, Suche RFD14N05 Datenblätter, PDF, Inventar bei Y-IC.com Online, Bestellen Sie RFD14N05 AMI Semiconductor / ON Semiconductor mit Garantie und Vertrauen. Anfrage RFD14N05: Info@Y-IC.com

Sie können auch interessiert sein:

 <p>RFD12N06RLESM9A Fairchild/ON Semiconductor MOSFET N-CH 60V 18A DPAK</p>	 <p>RFD14N05 Fairchild/ON Semiconductor MOSFET N-CH 50V 14A I-PAK</p>	 <p>RFD14N05L Fairchild/ON Semiconductor MOSFET N-CH 50V 14A I-PAK</p>	 <p>RFD14N05LSM AMI Semiconductor / ON Semiconductor MOSFET N-CH 50V 14A TO-252AA</p>
 <p>RFD14N05LM FAIRCHI RFD14N05LM FAIRCHI</p>	 <p>RFD140N05L FAIRCHI RFD140N05L FAIRCHI</p>	 <p>RFD12N06RLESM F RFD12N06RLESM F</p>	 <p>RFD14N05L AMI Semiconductor / ON Semiconductor MOSFET N-CH 50V 14A I-PAK</p>

heiße Teile

Mehr

 RFD10N05SM96	 RFD10P03L-251	 RFD10P03LSM	 RFD10P03LSM	 RFD10P05
 RFD12N06LE	 RFD12N06LESM	 RFD12N06REL	 RFD12N06RLE	 RFD12N06RLE
 RFD12N06RLESM	 RFD12N06RLESM9A	 RFD12N06RLESM9A	 RFD14N05	 RFD14N05L
 RFD14N05L	 RFD14N05LSM	 RFD14N05LSM	 RFD14N05LSM9A	 RFD14N05LSM9A
 RFD14N05SM	 RFD14N05SM	 RFD14N05SM9	 RFD14N05SM9A	 RFD14N05SM9A
 RFD15N05	 RFD15N05LSM	 RFD15N06LE	 RFD15N06LESM	 RFD15P05
 RFD15P05	 RFD15P05SM	 RFD15P05SM	 RFD15P05SM9A	 RFD15P06
 RFD15P06LSM	 RFD15P06SM	 RFD15P06SM9AS2463	 RFD16N02	 RFD16N02L
 RFD16N02LSM	 RFD16N02LSM9A	 RFD16N03L	 RFD16N03LSM	 RFD16N03LSM9A
 RFD16N05	 RFD16N05	 RFD16N05L	 RFD16N05LSM	 RFD16N05LSM

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